ES1A-ES1J

Surface Mount Rectifiers



VOLTAGE RANGE: 50 --- 600 V CURRENT: 1.0 A

Features

- ♦ Low cost
- ♦ Low leakage
- Low forward voltage drop
- High current capability
- Easily cleaned with Alcohol, Isopropanol and similar solvents
- ♦ The plastic material carries U/L recognition 94V-0

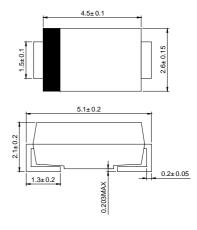
Mechanical Data

- ♦ Case:JEDEC DO-214AC, molded plastic
- ♦ Terminals: Solderable per

MIL- STD-202, Method 208

- ♦ Polarity: Color band denotes cathode
- ♦ Weight: 0.002 ounces, 0.064 grams
- Mounting position: Any

DO-214AC(SMA)



Dimensions in millimeters

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25°C ambient temperature unless otherwise specified.

Single phase, half wave, 60 Hz, resistive or inductive load. For capacitive load, derate by 20%.

		ES1A	ES1B	ES1C	ES1D	ES1G	ES1H	ES1J	UNITS
Maximum recurrent peak reverse voltage	V_{RRM}	50	100	150	200	400	500	600	V
Maximum RMS voltage	V _{RMS}	35	70	105	140	280	350	420	V
Maximum DC blocking voltage	V_{DC}	50	100	150	200	400	500	600	V
Maximum average forward rectified current @T _A =75°C	I _{F(AV)}	1.0							А
Peak forward surge current 8.3ms single half-sine-wave superimposed on rated load @T _J =125°C	I _{FSM}	30						А	
Maximum instantaneous forward voltage at1.0 A	V _F	0.98 1.25 1.70)	V		
	I _R	5.0 200						μА	
Typical reverse recovery time (Note1)	t _{rr}	35						ns	
Typical junction capacitance (Note2)	CJ	19							pF
Typical thermal resistance (Note3)	$R_{\theta JA}$	50						°C/W	
Operating junction temperature range	T _J	- 55 + 150						$^{\circ}$	
Storage temperature range	T _{STG}	- 55 + 150							$^{\circ}$

NOTE: 1. Measured with I_F =0.5A, I_R =1A, I_{rr} =0.25A.

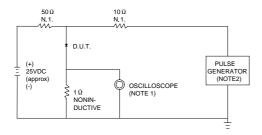
- 2. Measured at 1.0MHz and applied reverse voltage of 4.0V DC.
- 3. Thermal resistance from junction to ambient and junction to lead P.C.B.mounted on 0.27"X0.27"(7.0X7.0mm2) copper pad areas

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Ratings And Characteristic Curves

FIG.1 -- TEST CIRCUIT DIAGRAM AND REVERSE RECOVERY TIME CHARACTERISTIC



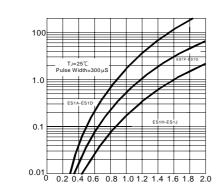
SET TIME BASE FOR 10/15 ns/cm

+0.5A

-0.25A

NOTES:1.RISE TIME = 7ns MAX.INPUT IMPEDANCE = 1M Ω .22pF. 2.RISE TIME =10ns MAX.SOURCE IMPEDANCE=50 Ω .

FIG.2 -- TYPICAL FORWARD CHARACTERISTIC



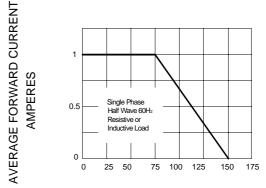
INSTANTANEOUS FORWARD CURRENT

JUNCTION CAPACITANCE, pF

AMPERES

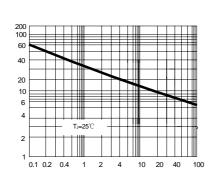
INSTANTANEOUS FORWARD VOLTAGE, VOLTS

FIG.3 -- FORWARD DERATING CURVE



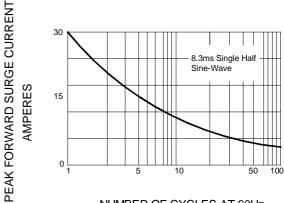
AMBIENT TEMPERATURE, ℃

FIG.4 -- TYPICAL JUNCTION CAPACITANCE



REVERSE VOLTAGE, VOLTS

FIG.5 -- PEAK FORWARD SURGE CURRENT



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